

## MBRF2035CT THRU MBRF20200CT

Isolation 20.0 AMPS. Schottky Barrier Rectifiers



Voltage Range Current

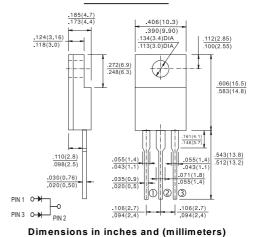
### **Features**

- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- High current capability, low forward voltage drop
- High surge capability
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- Guardring for overvoltage protection
- High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm)from case

#### Mechanical Data

- Cases: ITO-220AB molded plastic
- Terminals: Leads solderable per MIL-STD-750, ¢
- Method 2026
- $\diamond$ Polarity: As marked
- ¢ Mounting position: Any
- Mounting torque: 5 in. lbs. max
- Weight: 0.08 ounce, 2.24 grams

# 35 to 200 Volts 20.0 Amperes **ITO-220AB**



## Maximum Ratings and Electrical Characteristics

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	MBRF 2035 CT	MBRF 2045 CT	MBRF 2050 CT	MBRF 2060 CT	MBRF 20100 CT		MBRF 20200 CT	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	35	45	50	60	100	150	200	V
Maximum RMS Voltage	$V_{RMS}$	24	31	35	42	70	105	140	V
Maximum DC Blocking Voltage	$V_{DC}$	35	45	50	60	100	150	200	V
Maximum Average Forward Rectified Current at T <sub>c</sub> =135°C Total device Per Leg	I <sub>(AV)</sub>	20 10						Α	
Peak Repetitive Forward Current Per leg (Rated V <sub>R</sub> , Square Wave, 20KHz) at Tc=135°C	I <sub>FRM</sub>	20.0						Α	
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	150						Α	
Peak Repetitive Reverse Surge Current (Note 1)	$I_{RRM}$	1.0			0.5		Α		
Maximum Instantaneous Forward Voltage at (Note 2) $I_F=10A$ , $Tc=25^{\circ}C$ $I_F=10A$ , $Tc=125^{\circ}C$ $I_F=20A$ , $Tc=25^{\circ}C$ $I_F=20A$ , $Tc=125^{\circ}C$	V <sub>F</sub>	0.	- 57 84 72	0. 0. 0.	95	0.85 0.75 0.95 0.85	0.	99 87 23	٧
Maximum Instantaneous Reverse Current @ Tc=25℃ at Rated DC Blocking Voltage @ Tc=125℃	I <sub>R</sub>	0.1 15.0		0.15 150.0		m A			
Voltage Rate of Change, (Rated V <sub>R</sub> )	dV/dt	10,000						V/uS	
Typical Thermal Resistance Per Leg (Note 3) R $ heta$ JC	R $\theta$ JC	1.5			3.5		C/W		
Typical Junction Capacitance	Cj	400			310		рF		
RMS Isolation Voltage (MBRF Type Only) from Terminals to Heatsink with t=1.0 Second, RH $\leq$ 30%	V <sub>ISO</sub>	4500 (Note 4) 3500 (Note 5) 1500 (Note 6)						٧	
Operating Junction Temperature Range T <sub>J</sub>	ΤJ	-65 to +150					đ		
Storage Temperature Range TSTG	Tstg	-65 to +175						T	

Notes: 1. 2.0us Pulse Width, f=1.0 KHz

- 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle
- 3. Thermal Resistance from Junction to Case Per Leg, with Heatsink Size (4"x6"x0.25") Al-Plate
- 4. Clip mounting (on case), where lead does not overlap heatsink with 0.110" offset.
- 5. Clip Mounting (on case), where leads do overlap heatsink.
- 6. Screw Mounting with 4-40 screw, where washer diameter is  $\leq$  4.9 mm (0.19")



